

Ultrafast Diode

60 A, 400 V

FFH60UP40S, FFH60UP40S3

Description

The FFH60UP40S, FFH60UP40S3 is an ultrafast diode with low forward voltage drop and rugged UIS capability. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial applications as welder and UPS application.

Features

- Ultrafast Recovery, $T_{rr} = 85 \text{ ns}$ (@ $I_F = 60 \text{ A}$)
- Max Forward Voltage, $V_F = 1.3 \text{ V}$ (@ $T_C = 25^\circ\text{C}$)
- Avalanche Energy Rated
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

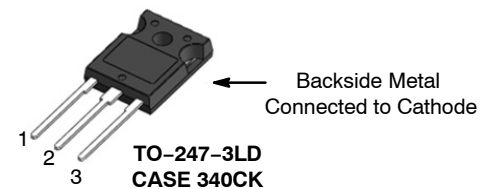
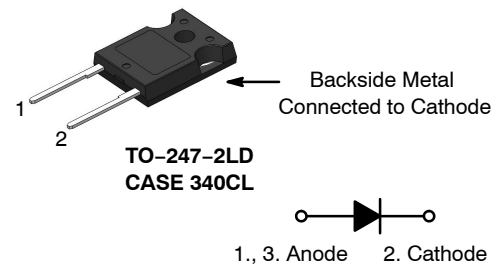
- General Purpose
- SMPS, Welder, UPS
- Free-wheeling Diode for Motor Application
- Power Switching Circuits



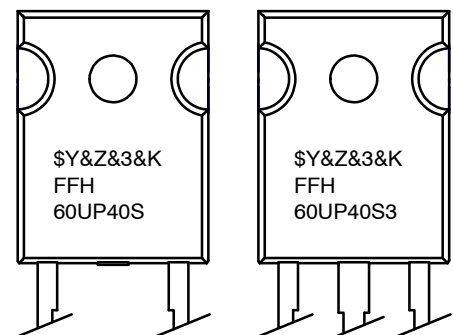
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PIN ASSIGNMENTS



MARKING DIAGRAM



| | |
|-------------|-------------------------|
| \$Y | = ON Semiconductor Logo |
| &Z | = Assembly Plant Code |
| &3 | = Numeric Date Code |
| &K | = Lot Code |
| FFH60UP40Sx | = Specific Device Code |

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFH60UP40S, FFH60UP40S3

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|-----------------------------------|--|-------------|------|
| V _{RRM} | Peak Repetitive Reverse Voltage | 400 | V |
| V _{RWM} | Working Peak Reverse Voltage | 400 | V |
| V _R | DC Blocking Voltage | 400 | V |
| I _{F(AV)} | Average Rectified Forward Current @ T _C = 139°C | 60 | A |
| I _{FSM} | Non-repetitive Peak Surge Current 60 Hz Single Half-Sine Wave | 600 | A |
| T _J , T _{STG} | Operating and Storage Temperature Range | -65 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Symbol | Parameter | Value | Unit |
|------------------|--|-------|------|
| R _{θJC} | Maximum Thermal Resistance, Junction to Case | 0.2 | °C/W |

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

| Symbol | Parameter | Min | Typ | Max | Unit | |
|-------------------------|--|------------------------|-----|------|------|----|
| V _F (Note 1) | I _F = 60 A | T _C = 25°C | - | 1.06 | 1.3 | V |
| | | T _C = 100°C | - | 0.99 | - | |
| I _R (Note 1) | V _R = 400 V | T _C = 25°C | - | - | 100 | μA |
| | | T _C = 100°C | - | - | 500 | |
| t _{rr} | I _F = 60 A, di _F /dt = 200 A/μs, V _R = 260 V | T _C = 25°C | - | 59 | 85 | ns |
| | | T _C = 100°C | - | 96 | - | |
| W _{AVL} | Avalanche Energy (L = 40 mH) | 50 | - | - | mJ | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse: Test Pulse Width = 300 μs, Duty Cycle = 2%

ORDERING INFORMATION

| Part Number | Device Marking | Package | Shipping |
|-------------|----------------|--|------------------|
| FFH60UP40S | FFH60UP40S | TO-247-2LD (Pb-Free / Halogen Free) | 450 Units / Tube |
| FFH60UP40S3 | FFH60UP40S3 | TO-247-3LD (Pb-Free / Halogen Free) | 450 Units / Tube |

FFH60UP40S, FFH60UP40S3

TEST CIRCUIT AND WAVEFORM

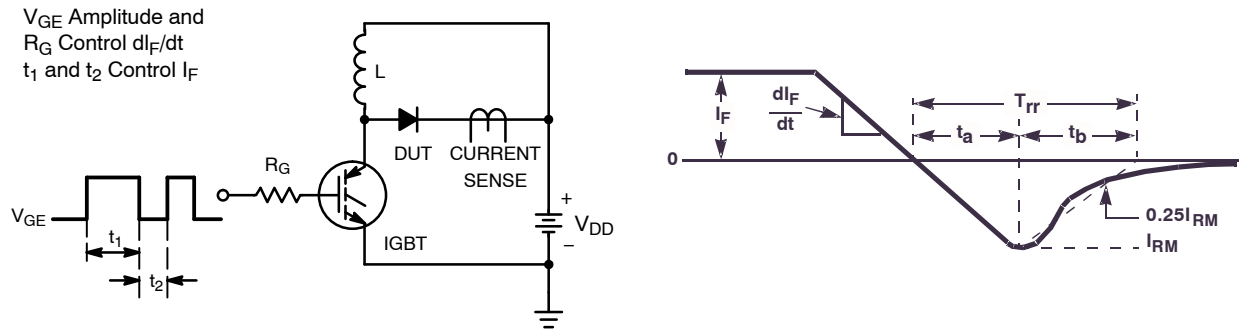


Figure 1. Diode Reverse Recovery Test Circuit and Waveform

$L = 40 \text{ mH}$
 $R < 0.1 \Omega$
 $V_{DD} = 50 \text{ V}$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)} / (V_{R(AVL)} - V_{DD})]$
 $Q1 = \text{IGBT } (BV_{CES} > \text{DUT } V_{R(AVL)})$

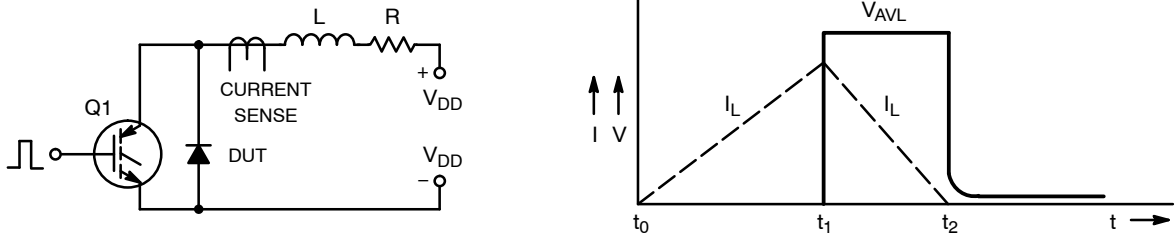


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

FFH60UP40S, FFH60UP40S3

TYPICAL PERFORMANCE CHARACTERISTICS

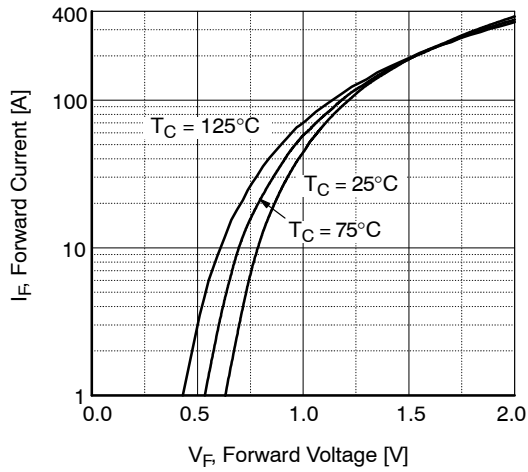


Figure 3. Typical Forward Voltage Drop vs. Forward Current

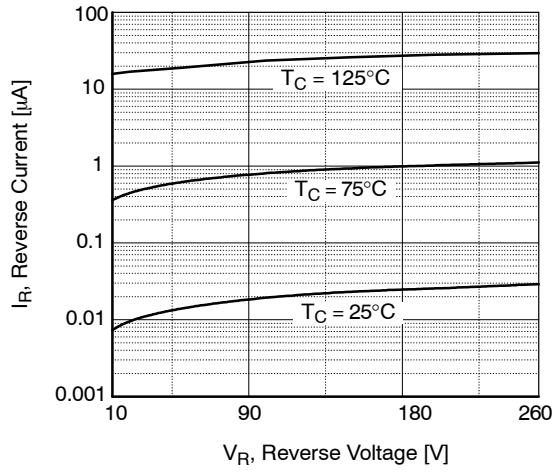


Figure 4. Typical Reverse Current vs. Reverse Voltage

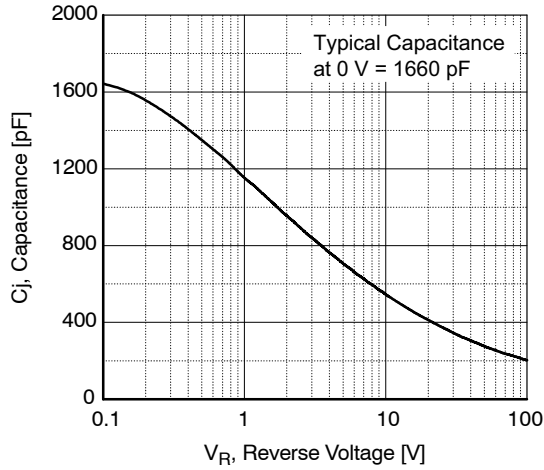


Figure 5. Typical Junction Capacitance

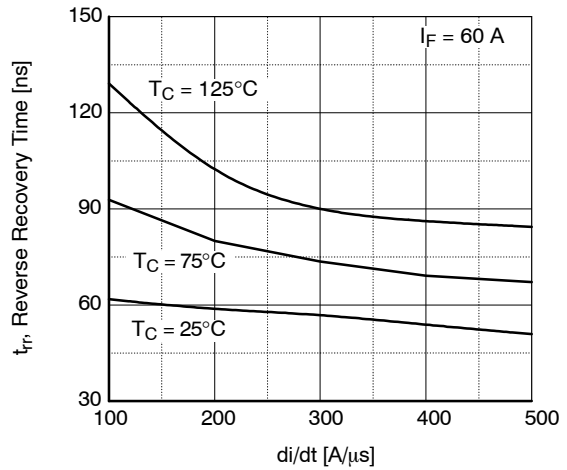


Figure 6. Typical Reverse Recovery Time vs. di/dt

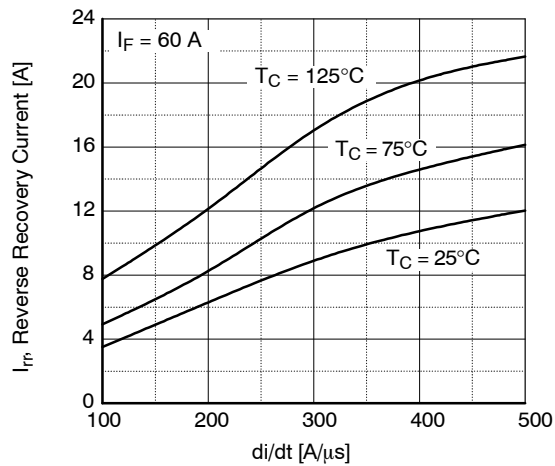


Figure 7. Typical Reverse Recovery Current vs. di/dt

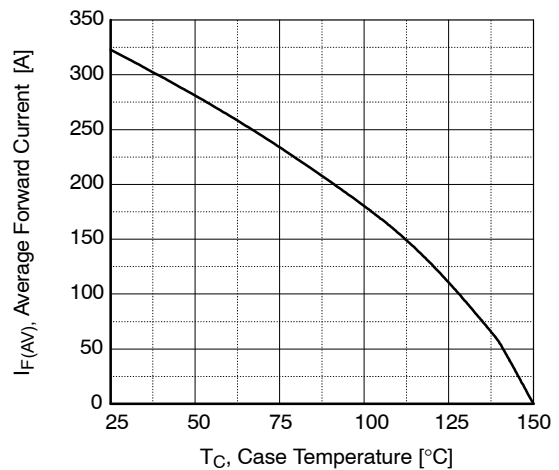
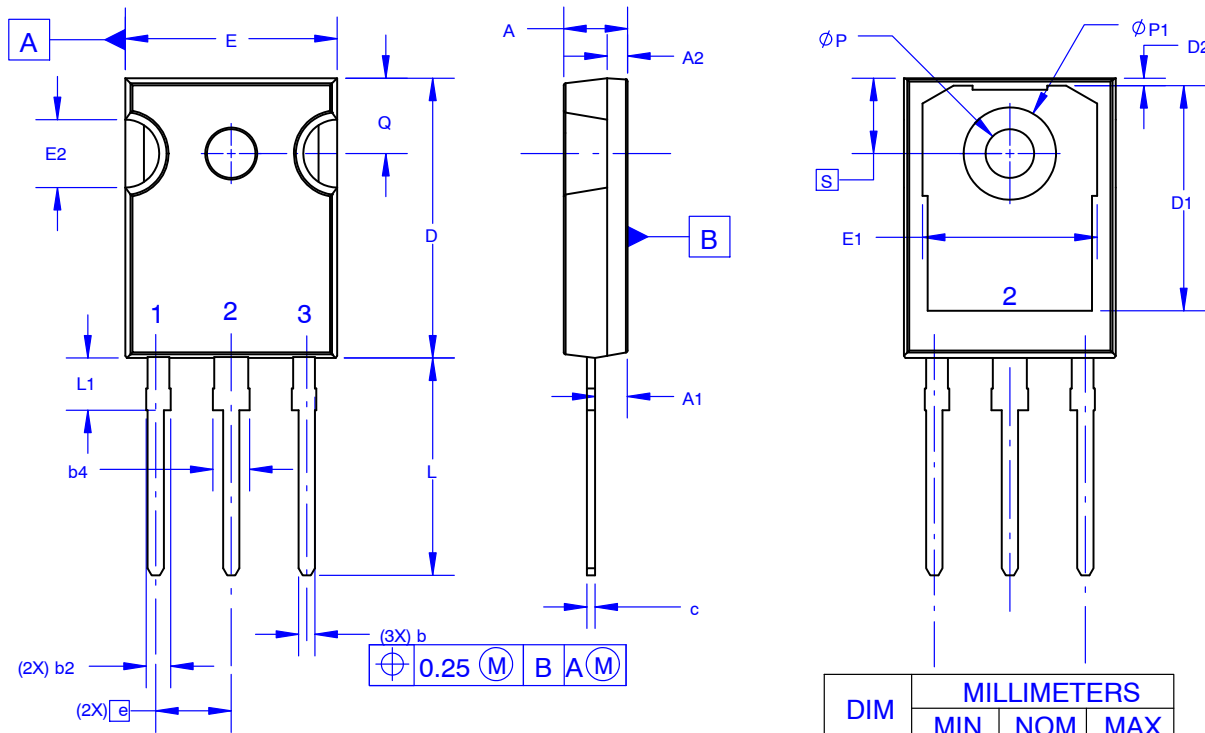


Figure 8. Forward Current Derating Curve

TO-247-3LD SHORT LEAD
CASE 340CK
ISSUE A

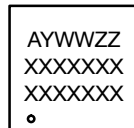
DATE 31 JAN 2019



NOTES: UNLESS OTHERWISE SPECIFIED.

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- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 - 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
 A = Assembly Location
 Y = Year
 WW = Work Week
 ZZ = Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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MECHANICAL CASE OUTLINE

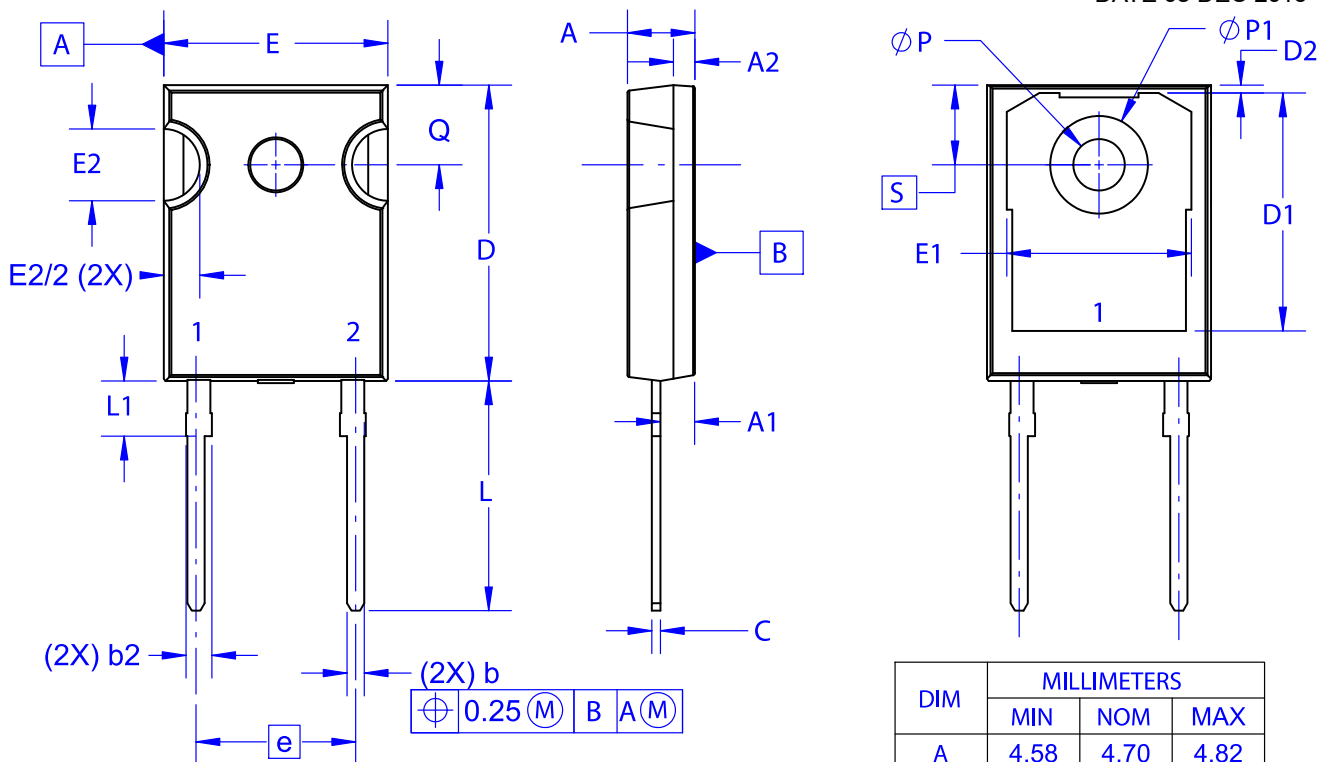
PACKAGE DIMENSIONS

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CASE 340CL
ISSUE A

DATE 03 DEC 2019

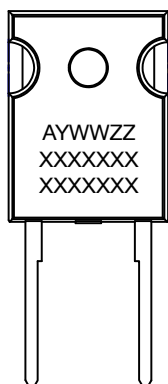


⊕ 0.25 (M) B A (M)

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| DIM | MILLIMETERS | | |
|-----|-------------|-------|-------|
| | MIN | NOM | MAX |
| A | 4.58 | 4.70 | 4.82 |
| A1 | 2.29 | 2.40 | 2.66 |
| A2 | 1.30 | 1.50 | 1.70 |
| b | 1.17 | 1.26 | 1.35 |
| b2 | 1.53 | 1.65 | 1.77 |
| c | 0.51 | 0.61 | 0.71 |
| D | 20.32 | 20.57 | 20.82 |
| D1 | 16.37 | 16.57 | 16.77 |
| D2 | 0.51 | 0.93 | 1.35 |
| E | 15.37 | 15.62 | 15.87 |
| E1 | 12.81 | ~ | ~ |
| E2 | 4.96 | 5.08 | 5.20 |
| e | ~ | 11.12 | ~ |
| L | 15.75 | 16.00 | 16.25 |
| L1 | 3.69 | 3.81 | 3.93 |
| ∅P | 3.51 | 3.58 | 3.65 |
| ∅P1 | 6.61 | 6.73 | 6.85 |
| Q | 5.34 | 5.46 | 5.58 |
| S | 5.34 | 5.46 | 5.58 |

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